## Features

- 3.3 V operating power supply with typical $11 \Omega$ switch connection between ports
- 5.0 V operating power supply with typical $5 \Omega$ switch connection between ports
- Bidirectional operation
- Ultra-low power CMOS technology
- ESD Rating HBM: 2000V, Class 2
- Signal Isolation: -60dB
- Channel Bandwidth (3dB): 500MHz
- Standard Microcircuit Drawing (SMD):
- 5962-15244
- QML Q and V compliant part
- Package Options: 20-Lead Flatpack


## Operational Environment

- Temperature Range: $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$
- Total Dose: $300 \mathrm{krad}(\mathrm{Si})$
- SEL Immune: $\leq 100 \mathrm{MeV}-\mathrm{cm}^{2} / \mathrm{mg}$


## Applications

- Memory Interface
- Bus Isolation
- Redundancy
- Supports Analog Applications


## Introduction

The UT54BS3245 provides 8 bits of high-speed CMOS-compatible bus switching. The low on-state resistance of the switch allows connections to be made with minimal propagation delay. The device is organized as one 8 -bit lowimpedance switch. When output enable (/EN) is low, the 8 -bit bus switch is on and port A is connected to port B . When /EN is high, the switch is open and a high-impedance state exists between the two ports.

8-bit Bus Switch

## UT54BS3245



## Pinlist

| TO | $=$ | TTL Output |
| :--- | :--- | :--- |
| TTB | $=$ | Three-State TTL Bidirectional |
| CI | $=$ | CMOS Input |
| TUI | $=$ | TTL Input (Internally Pulled High) |
| TI | $=$ | TTL Input |
| TTO | $=$ | Three-State TLL Output |
| DIO | $=$ | Differential Input/Output |

Table 1: Pinlist

| Number | Name | Description |
| :---: | :---: | :--- |
| $2,3,4,5,6,7,8,9$, | $n A$ | Port A Pins |
| $11,12,13,14,15,16,17,18$ | nB | Port B pins |
| 19 | $/ E N$ | Active LOW enable pin |
| 10 | $\mathrm{~V}_{\mathrm{SS}}$ | Ground Pin |
| 20 | $\mathrm{~V}_{\mathrm{DD}}$ | Supply Pin, +3.3V or +5.0V |
| 1 | NC | No Connect (electrically not connected to die) |

## Package Pinout Diagram



## Absolute Maximum Ratings ${ }^{1,2}$

Table 2: Absolute Maximum Ratings

| Symbol | Parameter | MIN | MAX | Units |
| :---: | :--- | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{DD}}$ | Positive Supply Voltage | -0.5 | +7.2 | V |
| $\mathrm{~V}_{\mathrm{I}}$ | Input Voltage | -0.5 | $\mathrm{~V}_{\mathrm{DD}}+0.3$ | V |
| $\mathrm{I}_{\mathrm{CCC}}$ | DC Channel Current |  | 65 | mA |
| $\mathrm{P}_{\mathrm{D}}$ | Max Power Dissipation ${ }^{(3)}$ |  | 1.6 | W |
| $\mathrm{~T}_{\mathrm{J}}$ | Junction Temperature |  | +150 | ${ }^{\circ} \mathrm{C}$ |
| $\theta_{\text {JC }}$ | Thermal resistance, junction-to-case |  | 15 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\mathrm{T}_{\text {STG }}$ | Storage Temperature | -65 | +150 | ${ }^{\circ} \mathrm{C}$ |
| ESD $_{\text {HBM }}$ | ESD Protection ${ }^{(4)}$ |  | 2000 | $\mathrm{~V}^{(2)}$ |

## Notes:

1) Stresses outside the listed absolute maximum ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond limits indicated in the operational sections of this specification are not recommended. Exposure to absolute maximum rating conditions for extended periods may affect device reliability and performance.
2) All voltages referenced to $V_{S S}$
3) Per MIL-STD-883, method 1012, section 3.4.1, $\left.\mathrm{P}_{\mathrm{D}}=\left(\mathrm{T}_{\mathrm{J}}(\max )-\mathrm{T}_{\mathrm{C}}(\max )\right) / \theta_{\mathrm{Jc}}\right)$
4) Per MIL-STD-883, method 3015, Table 3

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## Operational Environment ${ }^{(1)}$

Table 3: Operational Environment

| Symbol | Parameter | Limit | Units |
| :---: | :--- | :---: | :---: |
| TID | Total Ionizing Dose ${ }^{(2)}$ | 300 | $\mathrm{krad}(\mathrm{Si})$ |
| SEL | Single Event Latchup Immunity ${ }^{(3)}$ | $\leq 100$ | $\mathrm{MeV}^{2} \mathrm{~cm}^{2} / \mathrm{mg}$ |

## Notes:

1) For devices with procured with a total ionizing dose tolerance guarantee, post-irradiation performance is guaranteed at $25^{\circ} \mathrm{C}$ per MIL-STD-883 Method 1019, Condition A up to maximum TID level procured.
2) Per MIL-STD-883, method 1019, condition A
3) SEL is performed at VDD $=$ Max Voltage at $125^{\circ} \mathrm{C}$

## Recommended Operating Conditions ${ }^{(1)}$

Table 4: Recommended Operating Conditions

| Symbol | Parameter | Conditions | MIN | MAX | Units |
| :---: | :--- | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{DD}}$ | Positive Supply Voltage |  | 3.0 or 4.5 | 3.6 or 5.5 | V |
| $\mathrm{~V}_{\mathrm{IN}}$ | Input Voltage on any pin |  | 0.0 | $\mathrm{~V}_{\mathrm{DD}}$ | V |
| $\mathrm{T}_{\mathrm{C}}$ | Case Temperature Range |  | -55 | +125 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{t}_{\mathrm{R}}$ | Rise time, logic inputs | Transition from $\mathrm{V}_{\mathrm{IL}}$ to $\mathrm{V}_{\mathrm{IH}}$ |  | 5 | ns |
| $\mathrm{t}_{\mathrm{F}}$ | Fall time, logic inputs | Transition from $\mathrm{V}_{\mathrm{IH}}$ to $\mathrm{V}_{\mathrm{IL}}$ |  | 5 | ns |
| $\mathrm{I}_{\mathrm{CCC}}$ | DC Channel Current |  |  | 60 | mA |

## Note:

1) All voltages referenced to $V_{S S}$

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## DC Electrical Characteristics ${ }^{(1)}$

$\left(\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V} \pm 0.5 \mathrm{~V}, 3.3 \mathrm{~V} \pm 0.3 \mathrm{~V},-55^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{C}}<+125^{\circ} \mathrm{C}\right.$ ); Unless otherwise noted, $\mathrm{T}_{\mathrm{C}}$ is per the temperature range ordered

Table 5: DC Electrical Characteristics

| Symbol | Parameter | Conditions | MIN | MAX | Units |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{IH}}$ | High digital input voltage | $\mathrm{V}_{\mathrm{DD}}=3.6,5.5$ | 0.7* V ${ }_{\text {DD }}$ |  | V |
| $\mathrm{V}_{\text {IL }}$ | Low digital input voltage | $V_{D D}=3.0,4.5$ |  | 0.3* $\mathrm{V}_{\mathrm{DD}}$ | V |
| IID | Leakage current digital | $V_{\text {DD }}$ (max); $\mathrm{V}_{\mathrm{I}}=\mathrm{V}_{\mathrm{DD}}$ or $\mathrm{V}_{\text {SS }}$ | -1 | 1 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\mathrm{IA}}$ | Leakage current analog | $V_{D D}$ (max); $\mathrm{V}_{\mathrm{I}}=\mathrm{V}_{\mathrm{DD}}$ or $\mathrm{V}_{\text {SS }}$ | -1 | 1 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\mathrm{DD}}$ | Active supply current | $V_{D D}=3.6,5.5$ |  | 0.1 | $\mathrm{mA} / \mathrm{MHz}$ |
| $\mathrm{I}_{\mathrm{DDQ}}$ | Quiescent Supply Current | $\mathrm{V}_{\mathrm{DD}}(\mathrm{max}) ; \mathrm{I}_{\mathrm{O}}=0 \mathrm{~mA} ; / \mathrm{EN}=\mathrm{V}_{\mathrm{DD}}$ |  | 10 | $\mu \mathrm{A}$ |
| $\mathrm{C}_{\mathrm{I}}$ | Input Capacitance (/EN) ${ }^{(2)}$ | $\mathrm{V}_{\mathrm{I}}=\mathrm{V}_{\mathrm{DD}}$ or $\mathrm{V}_{\text {SS }}$ |  | 18 | pF |
| $\mathrm{Clo}_{\text {IOFF) }}$ | Channel pin capacitance (channel disabled) ${ }^{(2)}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}(\max ) ; \mathrm{V}_{\mathrm{O}}=\mathrm{V}_{\mathrm{DD}} \text { or } \mathrm{V}_{\mathrm{SS}} ; \mathrm{V}_{\mathrm{I}}=\mathrm{V}_{\mathrm{DD}} / 2 ; \\ & / \mathrm{EN}=\mathrm{V}_{\mathrm{DD}} \end{aligned}$ |  | 18 | pF |
| $\mathrm{R}_{\text {ONL }}$ | Resistance through switch (channel input low) ${ }^{(3)}$ | $\mathrm{V}_{\mathrm{DD}}=4.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{I}}=\mathrm{V}_{S S}, / E N=0 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=30 \mathrm{~mA}$ |  | 10 | $\Omega$ |
|  |  | $\mathrm{V}_{\mathrm{DD}}=4.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{I}}=\mathrm{V}_{S S}, / \mathrm{EN}=0 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=15 \mathrm{~mA}$ |  | 10 | $\Omega$ |
|  |  | $\mathrm{V}_{\mathrm{DD}}=3.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{I}}=\mathrm{V}_{\text {SS }}, / E N=0 \mathrm{~V}, \mathrm{I}_{0}=30 \mathrm{~mA}$ |  | 12 | $\Omega$ |
|  |  | $\mathrm{V}_{\mathrm{DD}}=3.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{I}}=\mathrm{V}_{S S}, / \mathrm{EN}=0 \mathrm{~V}, \mathrm{I}_{0}=15 \mathrm{~mA}$ |  | 12 | $\Omega$ |
| Ronh | Resistance through switch (channel input high) ${ }^{(3)}$ | $\mathrm{V}_{\mathrm{DD}}=4.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{I}}=\mathrm{V}_{\mathrm{DD}}, / \mathrm{EN}=0 \mathrm{~V}, \mathrm{I}_{0}=-30 \mathrm{~mA}$ |  | 10 | $\Omega$ |
|  |  | $\mathrm{V}_{\mathrm{DD}}=4.5 \mathrm{~V}, \mathrm{~V}_{\mathrm{I}}=\mathrm{V}_{\mathrm{DD}}, / \mathrm{EN}=0 \mathrm{~V}, \mathrm{I}_{0}=-15 \mathrm{~mA}$ |  | 10 | $\Omega$ |
|  |  | $\mathrm{V}_{\mathrm{DD}}=3.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{I}}=\mathrm{V}_{\mathrm{DD}}, / \mathrm{EN}=0 \mathrm{~V}, \mathrm{I}_{0}=-30 \mathrm{~mA}$ |  | 12 | $\Omega$ |
|  |  | $\mathrm{V}_{\mathrm{DD}}=3.0 \mathrm{~V}, \mathrm{~V}_{\mathrm{I}}=\mathrm{V}_{\mathrm{DD}}, / \mathrm{EN}=0 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=-15 \mathrm{~mA}$ |  | 12 | $\Omega$ |
| Ron(FLAT) | Switch on resistance ${ }^{(3)}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=4.5 \mathrm{~V}, / \mathrm{EN}=0 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=+/-15 \mathrm{~mA}, 25^{\circ} \mathrm{C} \\ & \mathrm{~V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{SS}}, \mathrm{~V}_{\mathrm{DD}} / 2, \mathrm{~V}_{\mathrm{DD}} \end{aligned}$ |  | 2 | $\Omega$ |
|  |  | $\begin{aligned} & \mathrm{V}_{\mathrm{DD}}=3.0 \mathrm{~V}, / \mathrm{EN}=0 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=+/-15 \mathrm{~mA}, 25^{\circ} \mathrm{C} \\ & \mathrm{~V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{SS}}, \mathrm{~V}_{\mathrm{DD}} / 2, \mathrm{~V}_{\mathrm{DD}} \end{aligned}$ |  | 10 | $\Omega$ |

## Notes:

1) All voltages referenced to $V_{S S}$
2) Per MIL-STD-883, method 3012
3) Guaranteed by Characterization

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## AC Electrical Characteristics ${ }^{1}$

$\left(\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V} \pm 0.5 \mathrm{~V}, 3.3 \mathrm{~V} \pm 0.3 \mathrm{~V},-55^{\circ} \mathrm{C}<\mathrm{T}_{\mathrm{C}}<+125^{\circ} \mathrm{C}\right.$ ); Unless otherwise noted, $\mathrm{T}_{\mathrm{c}}$ is per the temperature range ordered

Table 6: AC Electrical Characteristics

| Symbol | Parameter | Conditions | MIN | MAX | Units |
| :---: | :--- | :--- | :---: | :---: | :---: |
| $\mathrm{t}_{\text {PD15 }}$ | Channel Propagation Delay ${ }^{(1)}$ | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V} \pm 0.5 \mathrm{~V}, \mathrm{II}=+/-$ <br> $15 \mathrm{~mA}, / \mathrm{EN}=\mathrm{V}_{\mathrm{SS}}$ |  | 250 | ps |
| $\mathrm{t}_{\mathrm{EN}}$ | Channel Enable Delay ${ }^{(2)}$ | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V} \pm 0.5 \mathrm{~V}$ | 1 | 5 | ns |
| $\mathrm{t}_{\mathrm{DIS}}$ | Channel Disable Delay ${ }^{(2)}$ | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V} \pm 0.5 \mathrm{~V}$ | 1 | 5 | ns |
| $\mathrm{t}_{\mathrm{PD} 15}$ | Channel Propagation Delay ${ }^{(1)}$ | $\mathrm{V}_{\mathrm{DD}}=3.3 \mathrm{~V} \pm 0.3 \mathrm{~V}, \mathrm{II}=+/-$ <br> $15 \mathrm{~mA}, / \mathrm{EN}=\mathrm{V}_{\mathrm{SS}}$ |  | 250 | ps |
| $\mathrm{t}_{\mathrm{EN}}$ | Channel Enable Delay ${ }^{(2)}$ | $\mathrm{V}_{\mathrm{DD}}=3.3 \mathrm{~V} \pm 0.3 \mathrm{~V}$ | 1 | 7 | ns |
| $\mathrm{t}_{\mathrm{DIS}}$ | Channel Disable Delay ${ }^{(2)}$ | $\mathrm{V}_{\mathrm{DD}}=3.3 \mathrm{~V} \pm 0.3 \mathrm{~V}$ | 1 | 7 | ns |

## Notes:

1) The propagation delay through the channel is based on the RC time constant of the channel capacitance and maximum channel resistance for defined $V_{D D}$
2) Measured at 300 mV above or below steady state output voltage using output test load circuit

Table 7: Signal Characteristics

| Symbol | Parameter | Conditions | MIN | TYP | MAX | Units |
| :---: | :--- | :--- | :---: | :---: | :---: | :---: |
| $\mathrm{X}_{\text {TALK }}{ }^{1}$ | Channel Cross-Talk ${ }^{(1,2)}$ | $\mathrm{V}_{\mathrm{DD}}=5.0 \mathrm{~V}$ |  |  | -60 | dB |
| $\mathrm{X}_{\text {TALK }}{ }^{1}$ | Channel Cross-Talk $^{(1,2)}$ | $\mathrm{V}_{\mathrm{DD}}=3.3 \mathrm{~V}$ |  |  | -60 | dB |
| ISOoff $^{1}$ | Off Isolation ${ }^{(1,2)}$ |  |  |  | -60 | dB |

## Notes:

1) Guaranteed by design
2) $\mathrm{RL}=50 \Omega, C L=50 \mathrm{pF}$, fin $=1 \mathrm{MHz}$, Vin $=1 \mathrm{VRMS}$ centered at $\mathrm{V}_{\mathrm{DD}} / 2$

## Timing Diagram



Figure 3: Channel Propagations Delay (/EN = Vss)


Figure 4: Enable Timing

## Test Loads



Figure 5: Standard Test Load

## UT54BS3245

## Package Drawings



Figure 6: 20-Lead Flatpack

## Notes:

1) The Lid Is Connected to VSS.
2) Dimensions are in Millimeters.

## Ordering Information

## Generic Datasheet Part Numbering



Notes:

1) Lead finish (A, C, F, or X) must be specified.
2) If an " $X$ " is specified when ordering, then the part marking will match the lead finish applied to the device shipped
3) Prototype Flow per CAES Manufacturing Flows Document. Lead finish is Factory Option " C " only. Radiation is neither tested nor guaranteed.
4) HiRel Flow per CAES Manufacturing Flows Document. Radiation TID tolerance may (or may not) be ordered.

## UT54BS3245

## Ordering Information

## SMD Part Numbering



Federal Stock Class Designator

## Notes:

1) Lead finish must be specified. If " $X$ " is specified when ordering, the factory will determine lead finish. Part marking will reflect the lead finish applied to the device shipped.
2) A radiation hardness assurance level must be selected. The use of "-" indicates no radiation hardness assurance guarantee.

## Revision History

Table 8: Revision History

| Date | Rev. \# | Change Description | Initials |
| :---: | :---: | :--- | :---: |
| $05 / 01 / 2016$ | 1.0 .0 | Updated datasheet to reflect CAES logo, colors, and modified format. Updated the <br> following specifications: RoN, $I_{I A}, I_{D D}, I_{D D Q}, T_{\text {EN }}$, and $T_{\text {DIS. }}$ | MM |
| $06 / 23 / 2016$ | 2.0 .0 | Released Datasheet. Updated capacitance, propagation delay, and minor formatting. | BM |
| $6 / 30 / 2016$ | 2.0 .1 | FEATURES: 20-Lead Flatpack; IDDQ: CONDITIONS: /EN=VDD | BM |
| $01 / 04 / 2017$ | 2.0 .2 | FEATURES: QML Q, V compliant part | BM |
| $09 / 12 / 2019$ | 2.0 .3 | Package Pinout Diagram, Fig. 2, p.3 - Error Correction: Pins $11-14$ | BM |
| $08 / 19 / 2021$ | 2.0 .5 | ROC Table, p.4: Input $\mathrm{t}_{\mathrm{R}}, \mathrm{t}_{\mathrm{F}}$ parameter updates. | BM |

Datasheet Definitions

|  |  |
| :--- | :--- |
| Advanced Datasheet | CAES reserves the right to make changes to any products and services <br> described herein at any time without notice. The product is still in the <br> development stage and the datasheet is subject to change. <br> Specifications can be TBD and the part package and pinout are not final. |
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